

Simultaneous Removal of Alumina Particles and Dissolved Copper from Copper-CMP Waste Streams

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Overview of Copper CMP

- Slurries for copper CMP are either alumina or silica based.
- Hydrogen peroxide is the most commonly used oxidant in the slurries.
- Slurries may contain an organic complexant for copper.
- Benzotriazole(BTA) is added to the slurries to inhibit copper corrosion.
- Copper polishing is typically carried out in the pH range of 6 to 7.
- Barrier layer removal follows copper polishing.
- If the barrier layer used is Ta, polishing at an alkaline pH may be required to remove Ta.
- Some new slurries which can remove Ta at acidic pH values have been developed (EKC).
- An oxide buffing step to remove contaminants may be used.
- In **summary**, wastes from copper and tantalum removal steps as well as that from oxide buffing fall under the general category of “**Copper CMP WASTES**”



Cu-CMP Waste Characteristics

A typical copper CMP waste contains:

- **0.02 – 0.5 w/v% solids**
- **2 – 40ppm copper ions**
- **An organic complexant?
(e.g. EDA, EDTA, CA)**
- **A corrosion inhibitor
(e.g. BTA)**

Slurry Waste	Cu level (ppm)	pH	Conductivity ($\mu\text{S}/\text{cm}$)
A	TBD	~6.5	~568
B	TBD	~3.6	~395
C	40	~8.5	~1300

A suspension with the following characteristics was used to simulate copper CMP waste:

- $\approx 0.4\text{w/v}\%$ Al_2O_3
(average particle size $\approx 200\text{nm}$)
- $\approx 40\text{ppm}$ copper ions
- $\approx 185\text{ppm}$ EDTA
(ethylenediamine tetraacetic acid)
or 37.8 ppm EDA
(ethylenediamine)
- $\text{pH} \approx 6.0$
- Conductivity $\approx 1300\mu\text{S}/\text{cm}$



Environmental Regulations

Total Suspended Solids (TSS) level*:

- San Jose Code Limitations: TSS = 0 ppm
- Austin Code Limitations: TSS = 200 ppm
- Puyallup Code Limitation: TSS = 0.015 ppm

Cu Level in Aqueous Phase*:

- San Jose Code Limitations: Cu level = 2.7 ppm
- Austin Code Limitations: Cu level = 1.9 ppm
- Puyallup Code Limitation: Cu level = 0.024 ppm

Cu Level in Solid:

EPA: 40 CFR 503 in RCRA (Resource Conservation Recovery Act):

To qualify for land application, sewage sludge must meet at least the **Pollutant Ceiling Concentrations** (PCL):

The land application pollutant limits (PCL) for Copper = 4.3 g/kg

(* Corlett, G.L., Advancing applications in Contamination Control, p.19, Dec. 1998)



Objectives

1. Removal of suspended solids without adding any “additional” chemicals.
2. Simultaneously remove dissolved copper to facilitate water recycle and meet environmental regulations.



Techniques Used

- **Electrodecantation/Electrocoagulation**

solid/liquid separation assisted by the application of an electric field.

- **Electrodeposition**

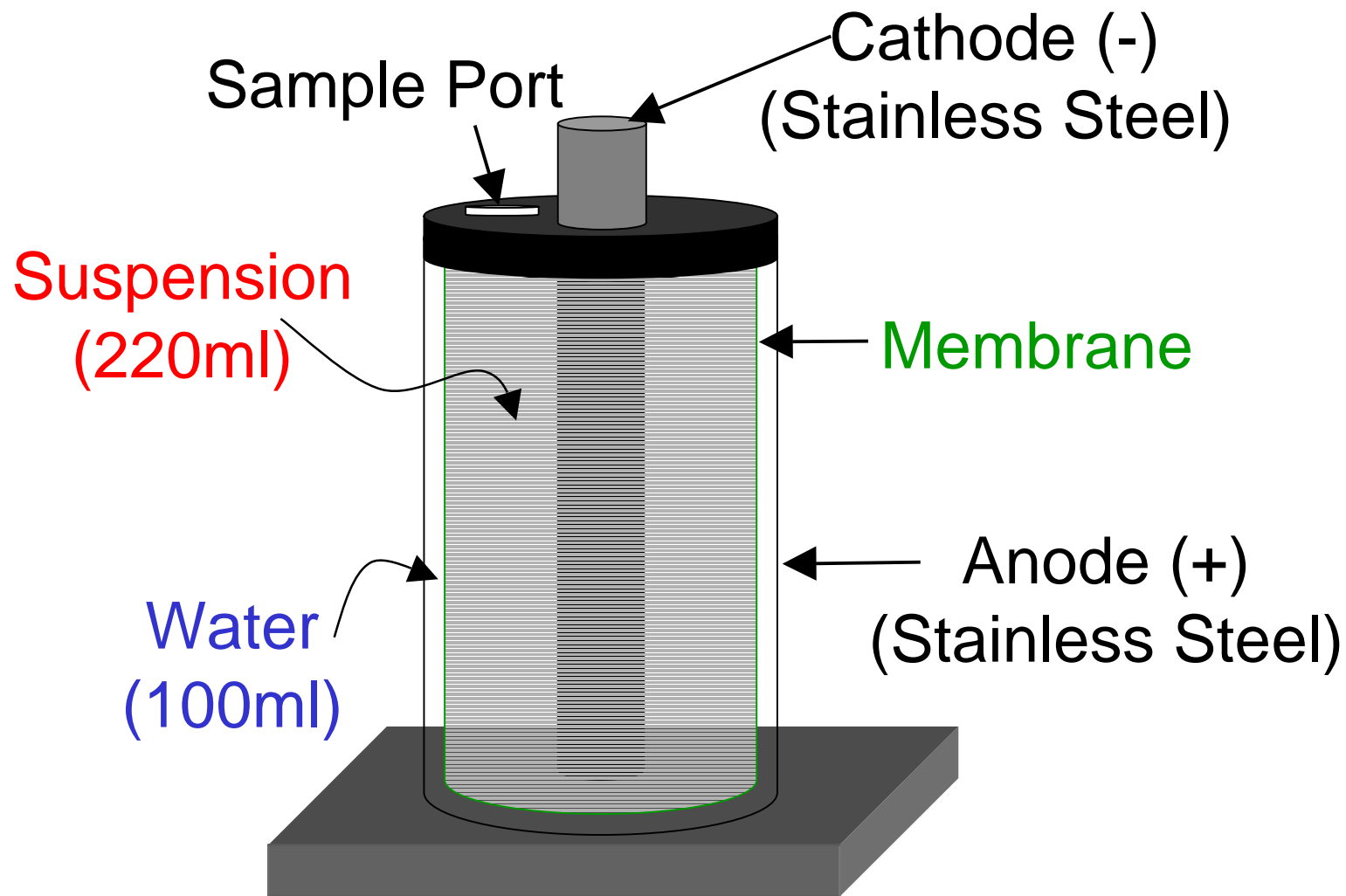
plate out copper

- **In-situ chemical precipitation**

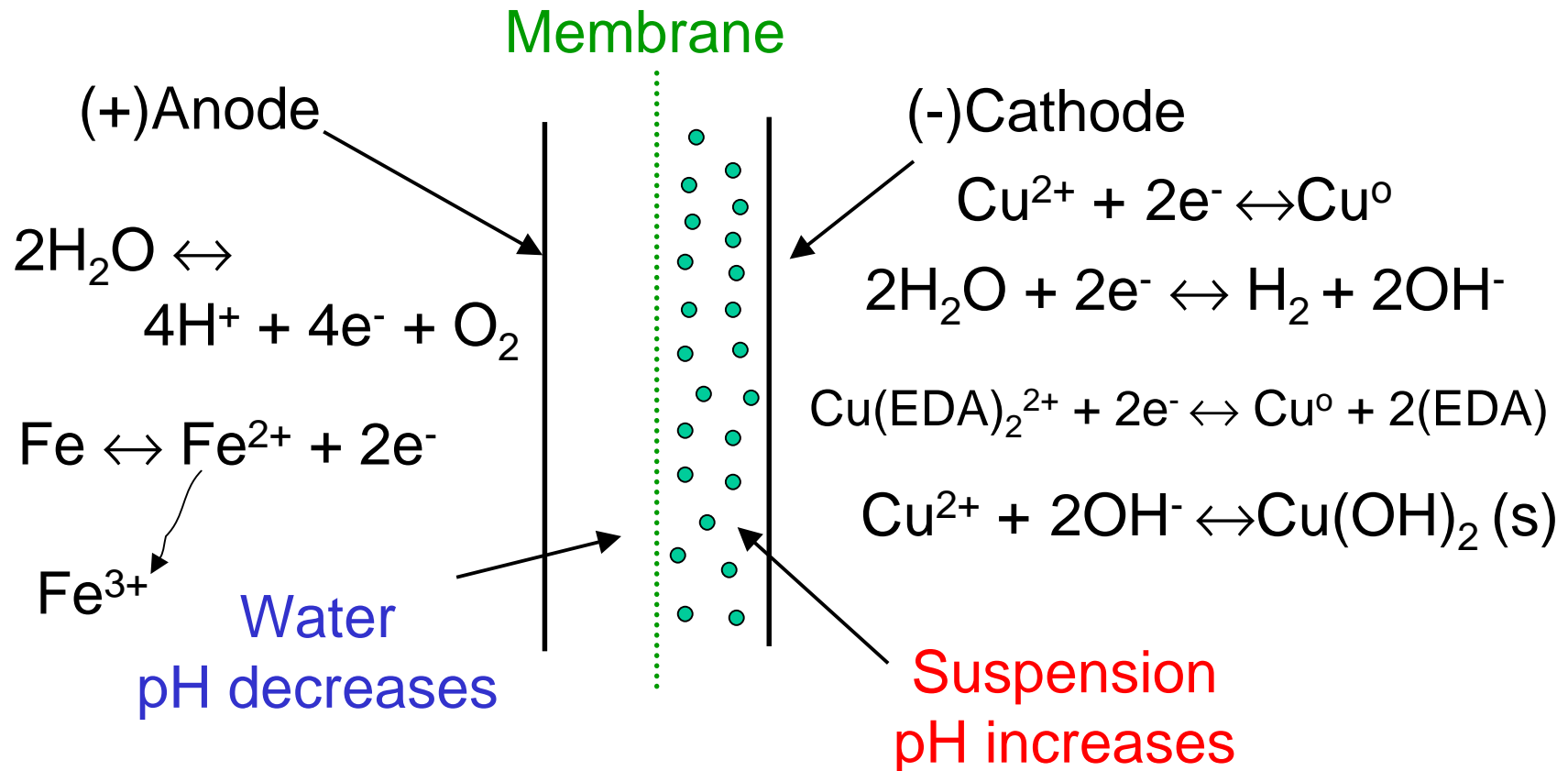
remove copper as $\text{Cu}(\text{OH})_2$



Experimental Setup



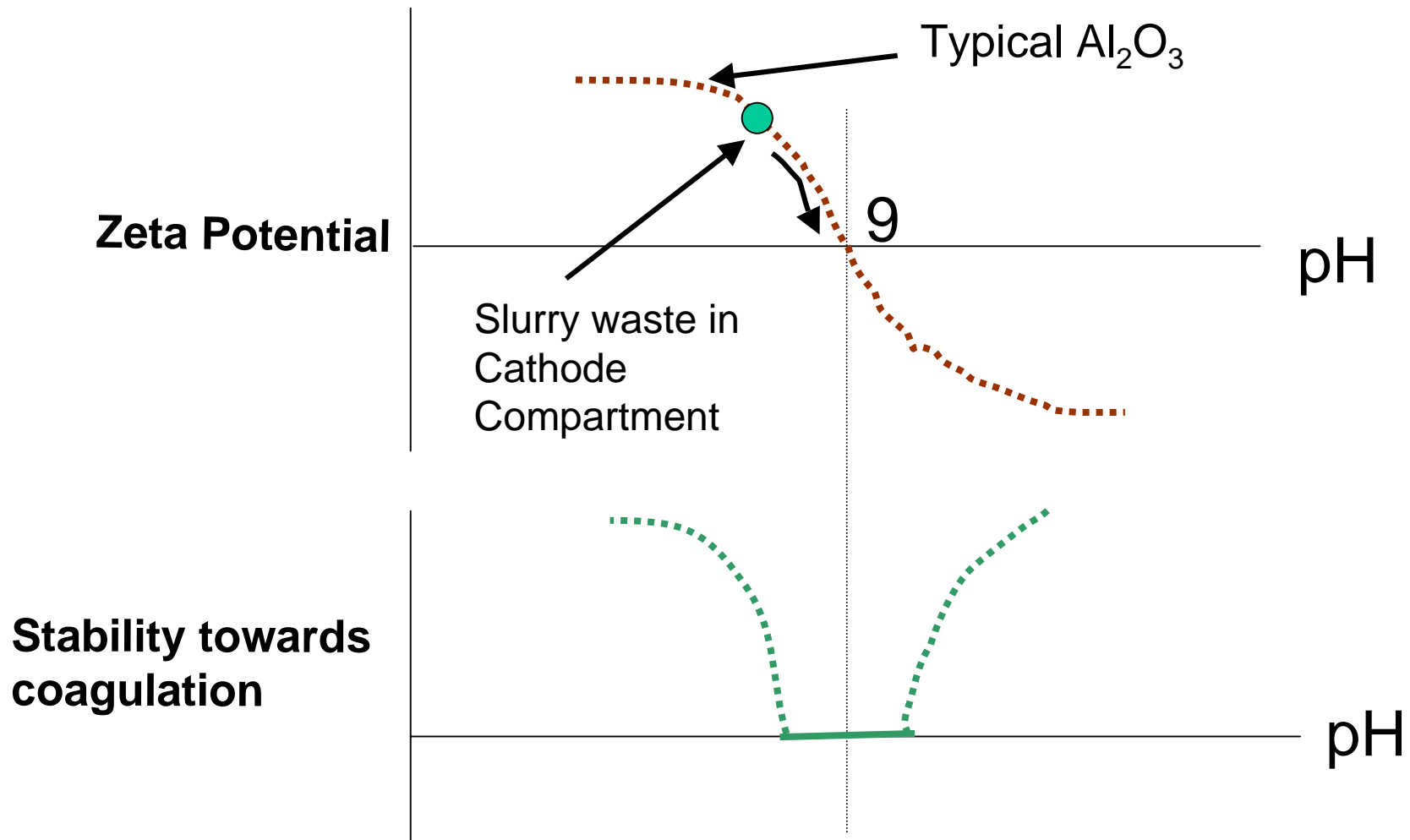
Copper Removal



- The **membrane** partitions the anode and cathode chambers, allowing pH changes to occur in the anode and cathode compartments.



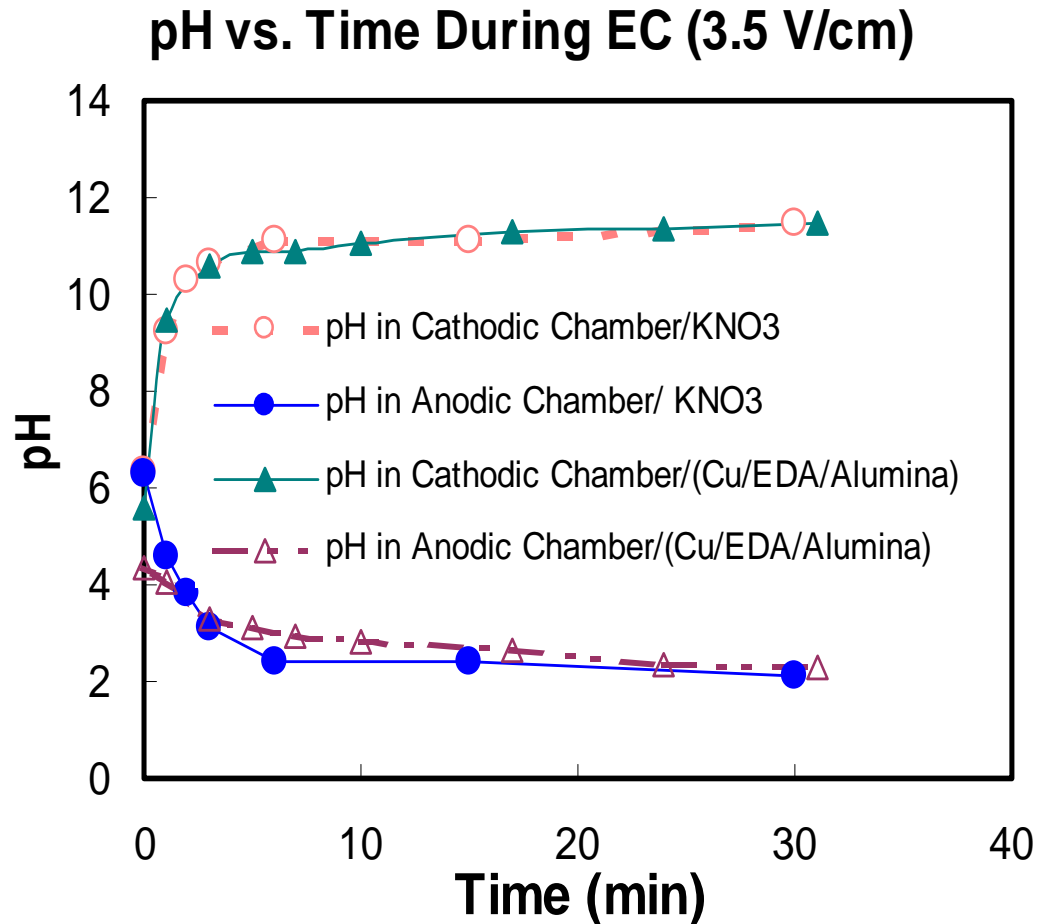
Solids Removal (underlying concept)



- pH in the Cathode compartment increases due to the generation of OH⁻



pH Changes during Electrocoagulation

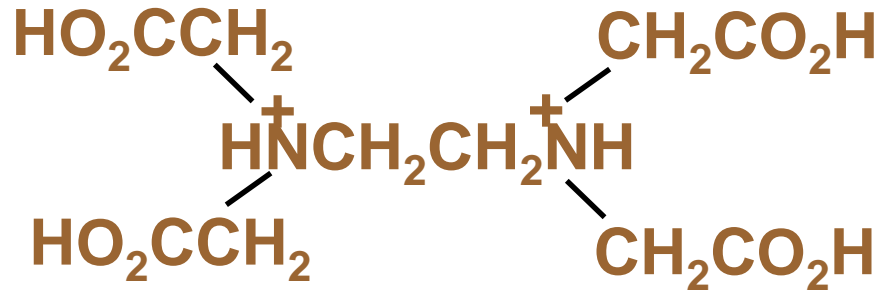


- The suspension pH increases rapidly when an electric field is applied.

- If IEP of Al₂O₃ particles in the cathode chamber is between $4 < \text{pH} < 10$, coagulation of particles may occur as pH approaches the IEP of particles.



EDTA Characteristics



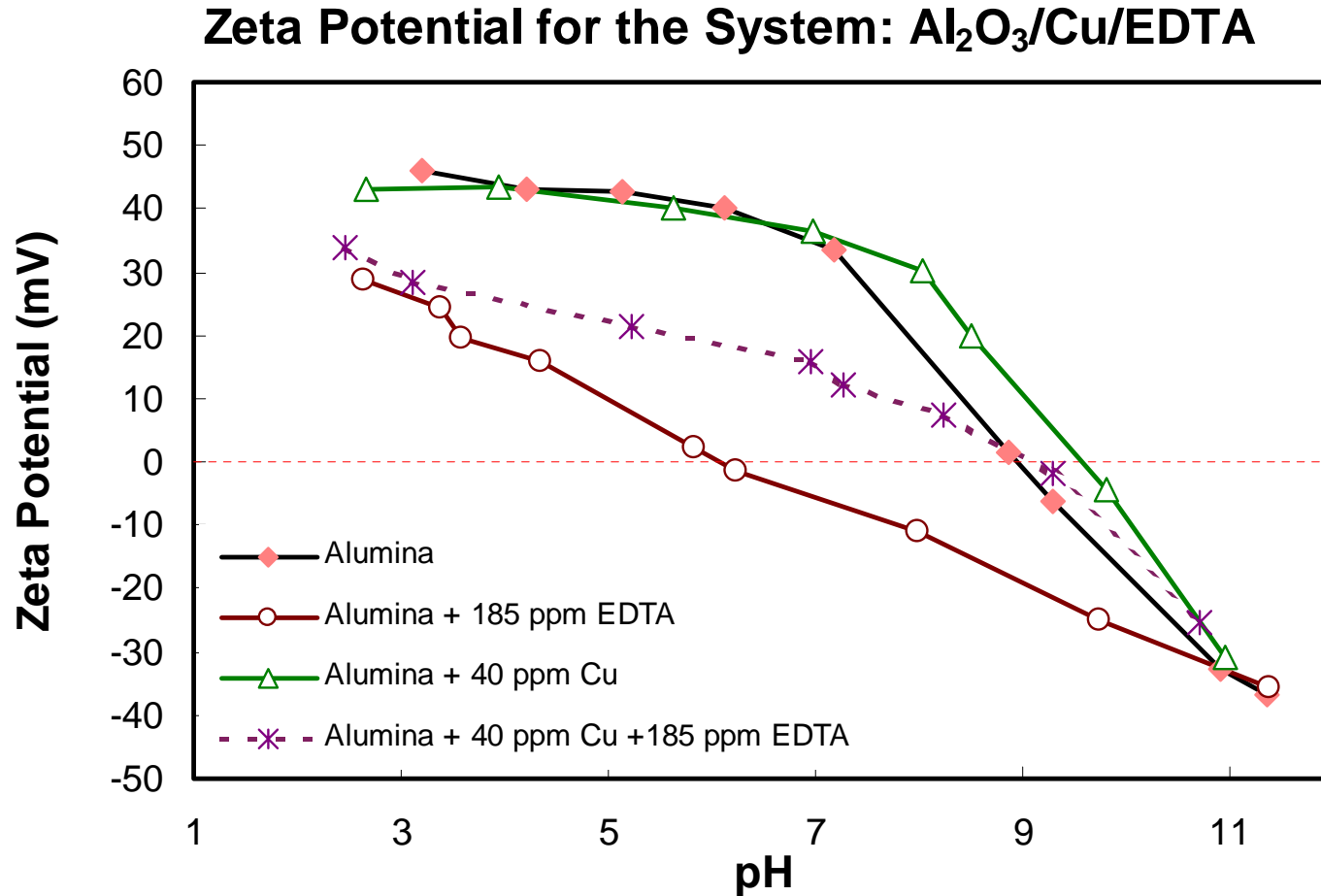
$$\begin{aligned} pK_1 &= 0.0 & pK_4 &= 2.7 \\ pK_2 &= 1.5 & pK_5 &= 6.2 \\ pK_3 &= 2.0 & pK_6 &= 10.2 \end{aligned}$$

pH	Charge of Cu(EDTA) complex
1.0	+3
1.7	+2
2.5	+1
5.0	0
8.0	-1
11.0	-2

- EDTA forms a 1:1 complex with Cu
- The charge of the Cu(EDTA) complex depends on the suspension pH



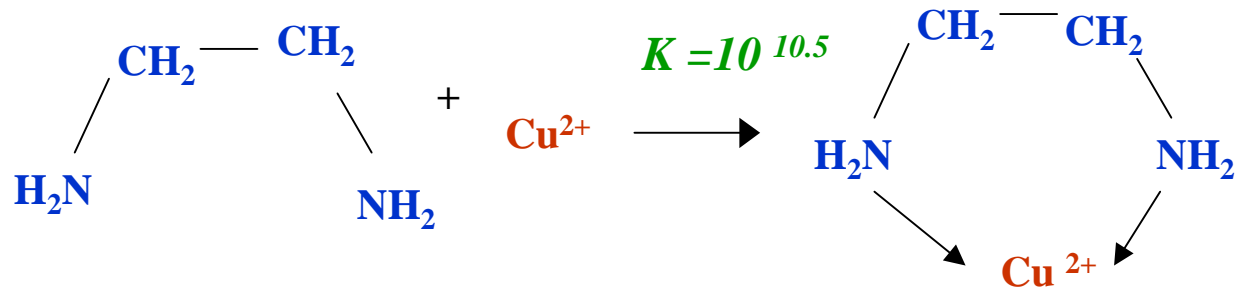
Electrokinetic Behavior of Al_2O_3 (1)



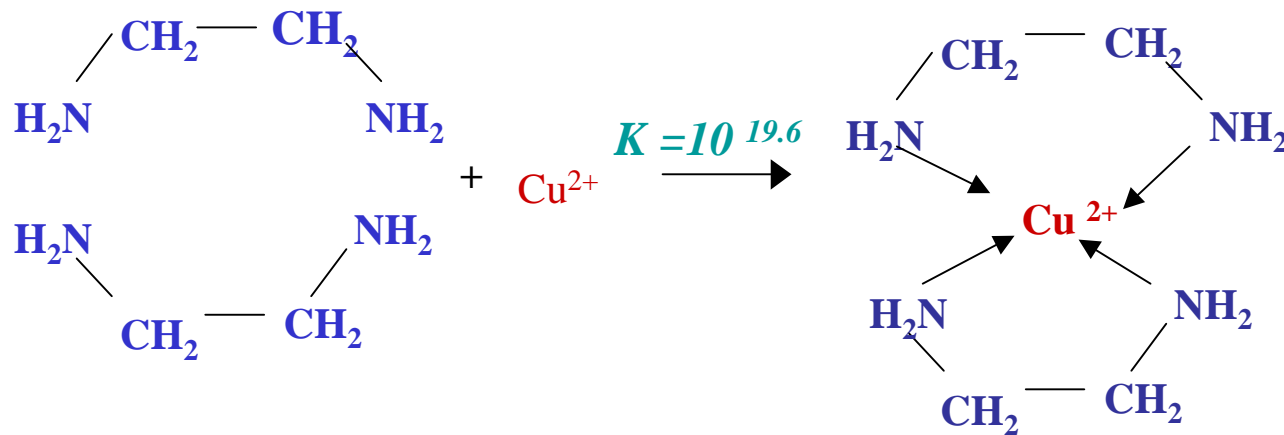
- EDTA shifts the isoelectric point of Al_2O_3 to lower pH values.
- $\text{Cu}(\text{EDTA})$ complex has no significant effect on the IEP of Al_2O_3



EDA Characteristics



or

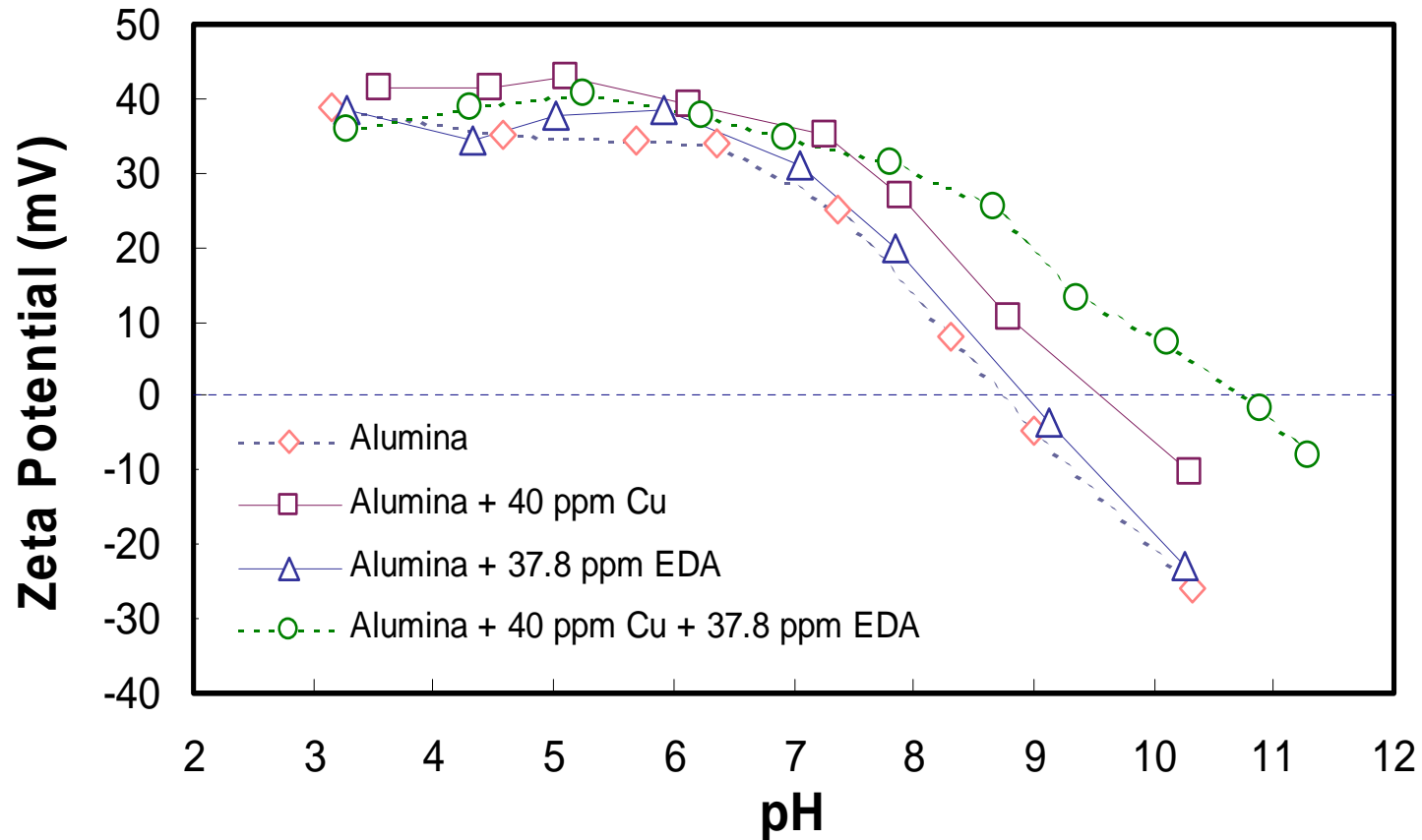


- EDA forms a 1:1 or 2:1 complex with Cu
- The charge of the $\text{Cu}(\text{EDA})$ or $\text{Cu}(\text{EDA})_2$ complex is positive.



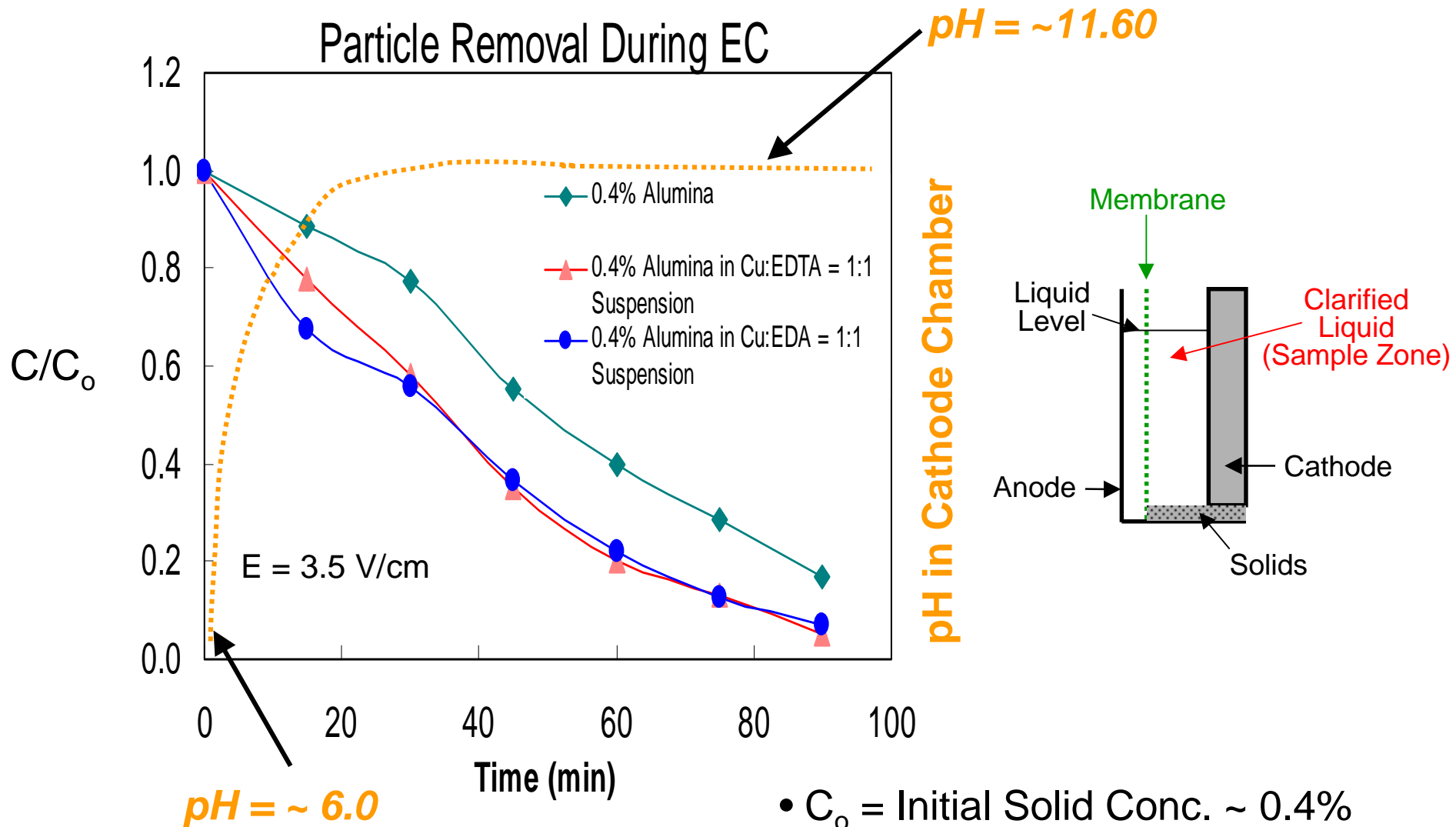
Electrokinetic Behavior of Al_2O_3 (2)

Zeta Potential for the System: $\text{Al}_2\text{O}_3/\text{Cu}/\text{EDA}$



- EDA does not effect the isoelectric point of Al_2O_3 .
- $\text{Cu}(\text{EDA})$ complex shifts the IEP of Al_2O_3 to higher pH values.

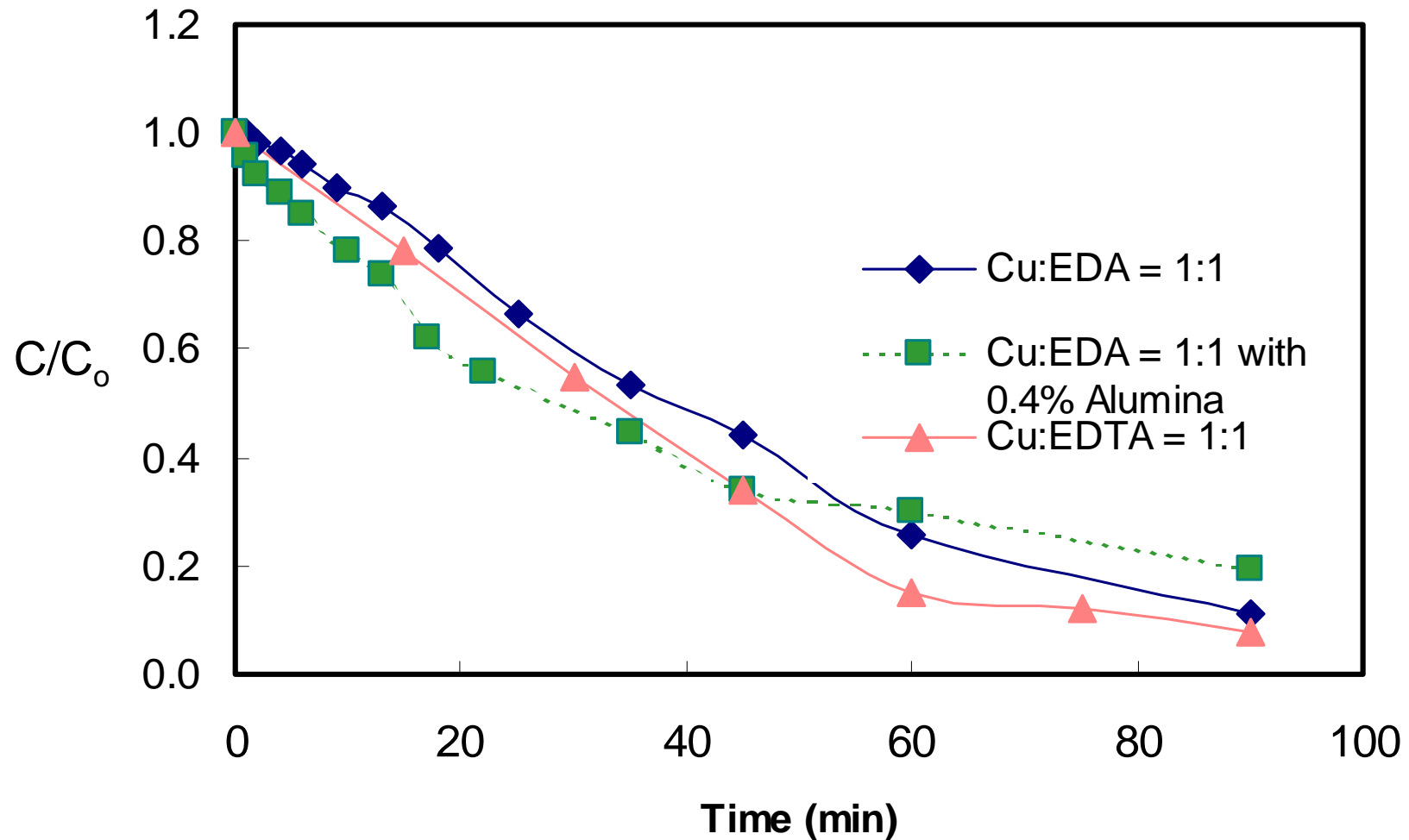




- C_0 = Initial Solid Conc. $\sim 0.4\%$
- C = Solid Concentration

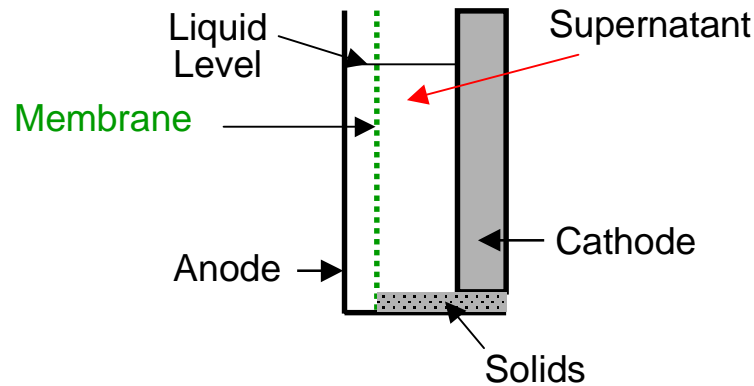


Kinetics of Removal of Dissolved Copper



•Copper is removed by plating and/or by copper hydroxide formation in the bulk.

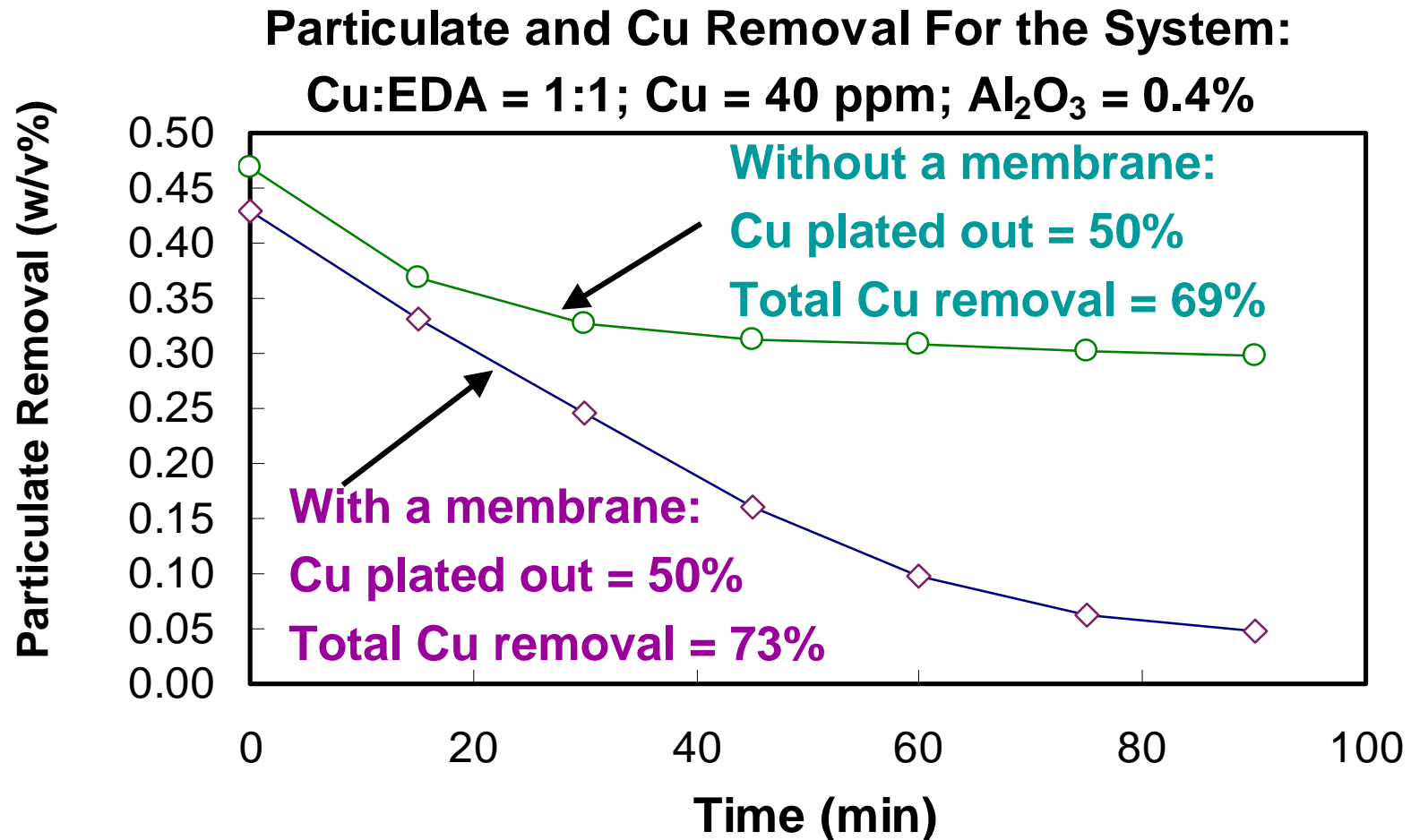




EDTA (Cu:EDTA = 1:1; Cu _{oCu} = 40 ppm)		EDA (Cu:EDA = 1:1; Cu _{oCu} = 40 ppm)	
Forms negatively charged Cu-EDTA complexes.		Forms positively charged Cu-EDA complexes.	
Electric potential restrains Cu-EDTA complexes from approaching cathode		Electric potential attracts Cu-EDA complexes to cathode	
Cu(EDTA) ²⁻ ; log K = 20.5	E = -0.27 V	Cu(EDA) ⁺ ; log K = 10.5	E = 0.03 V
% Cu plated out	16.3%	% Cu plated out	50.2%
% Cu Collected with solid	39.4%	% Cu Collected with solid	25.3%
% Cu in anode chamber/supernatant	20.5/9.7 %	% Cu in anode chamber/supernatant	0.0/15.3%

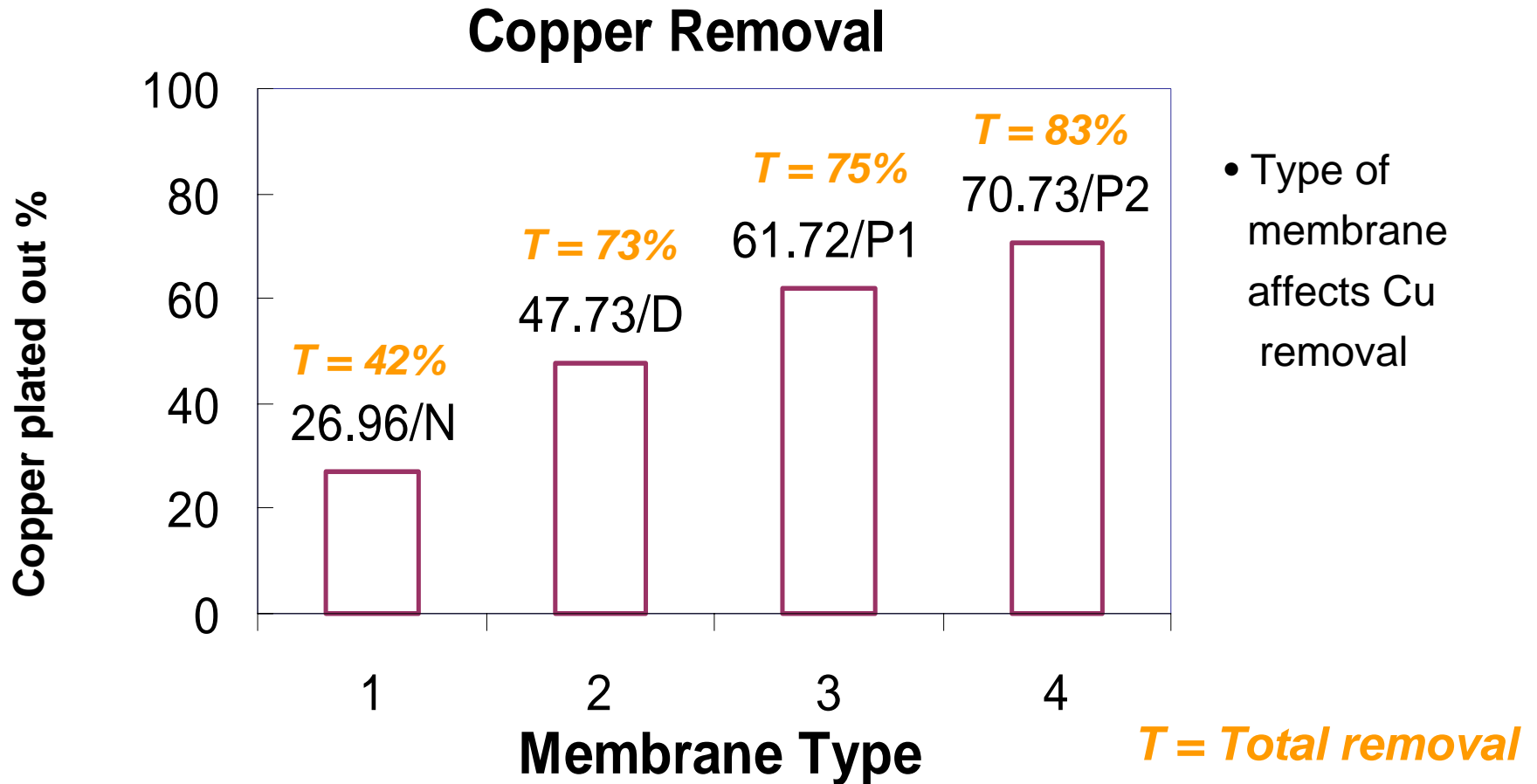


Effect of Membrane on Particulate and Cu Removal



- The presence of a membrane enhanced the removal of particulate.

Effect of Membrane Type on Particulate and Cu Removal

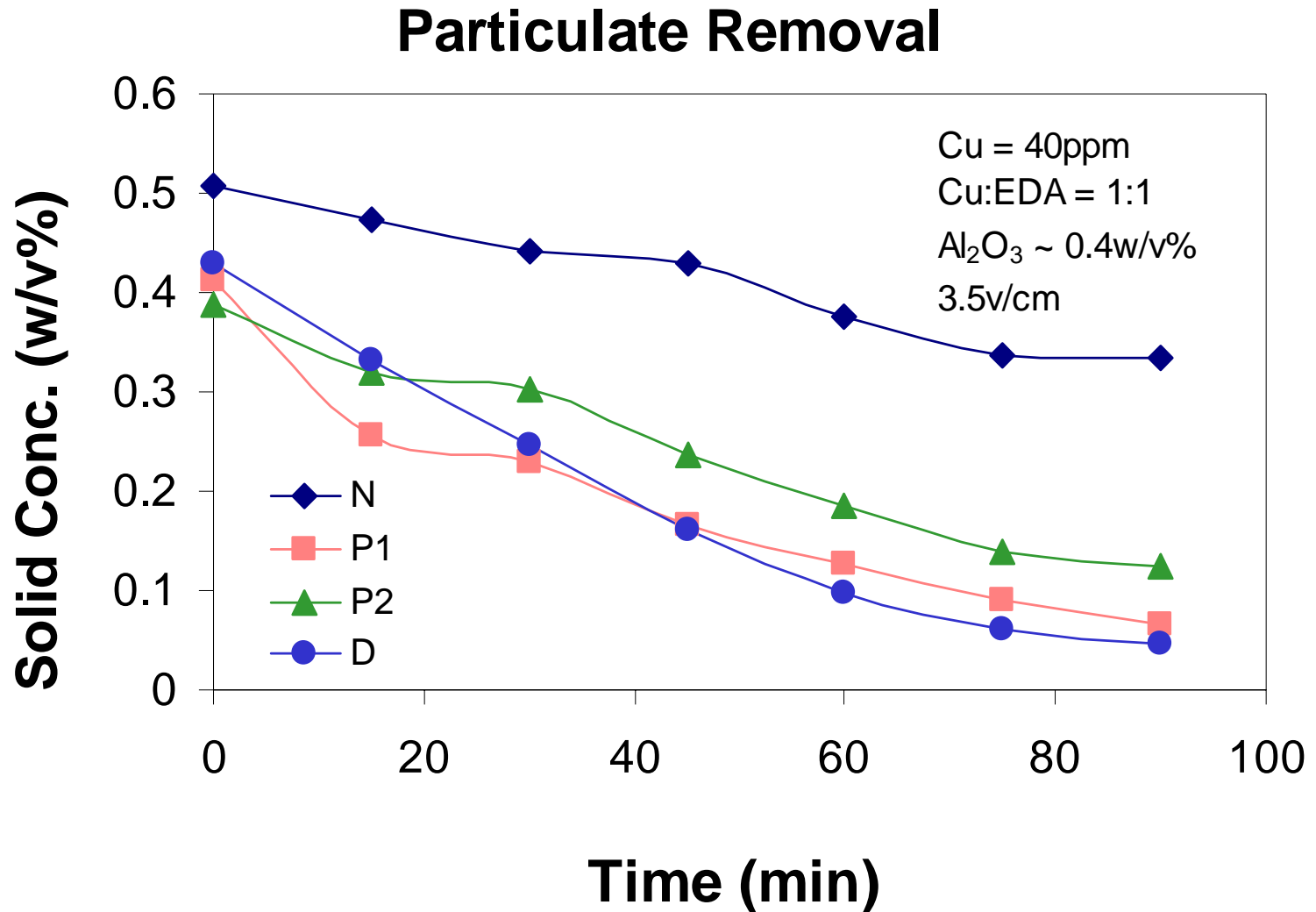


N -- negatively charged membrane; D -- dialysis membrane

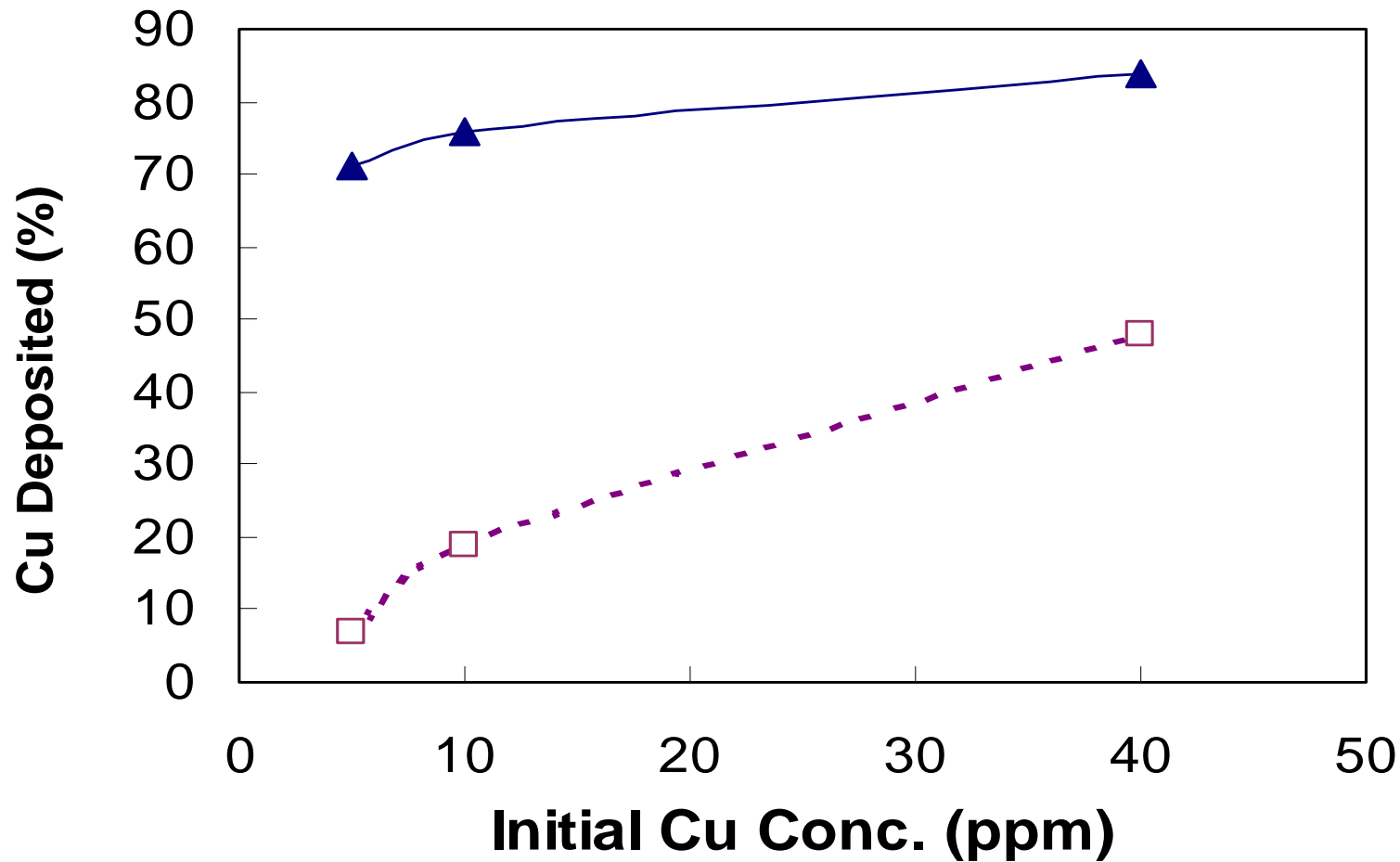
P1-- positively charged membrane; P2 -- positively charged membrane



Effect of Membrane Type on Particulate & Cu Removal -- (2)



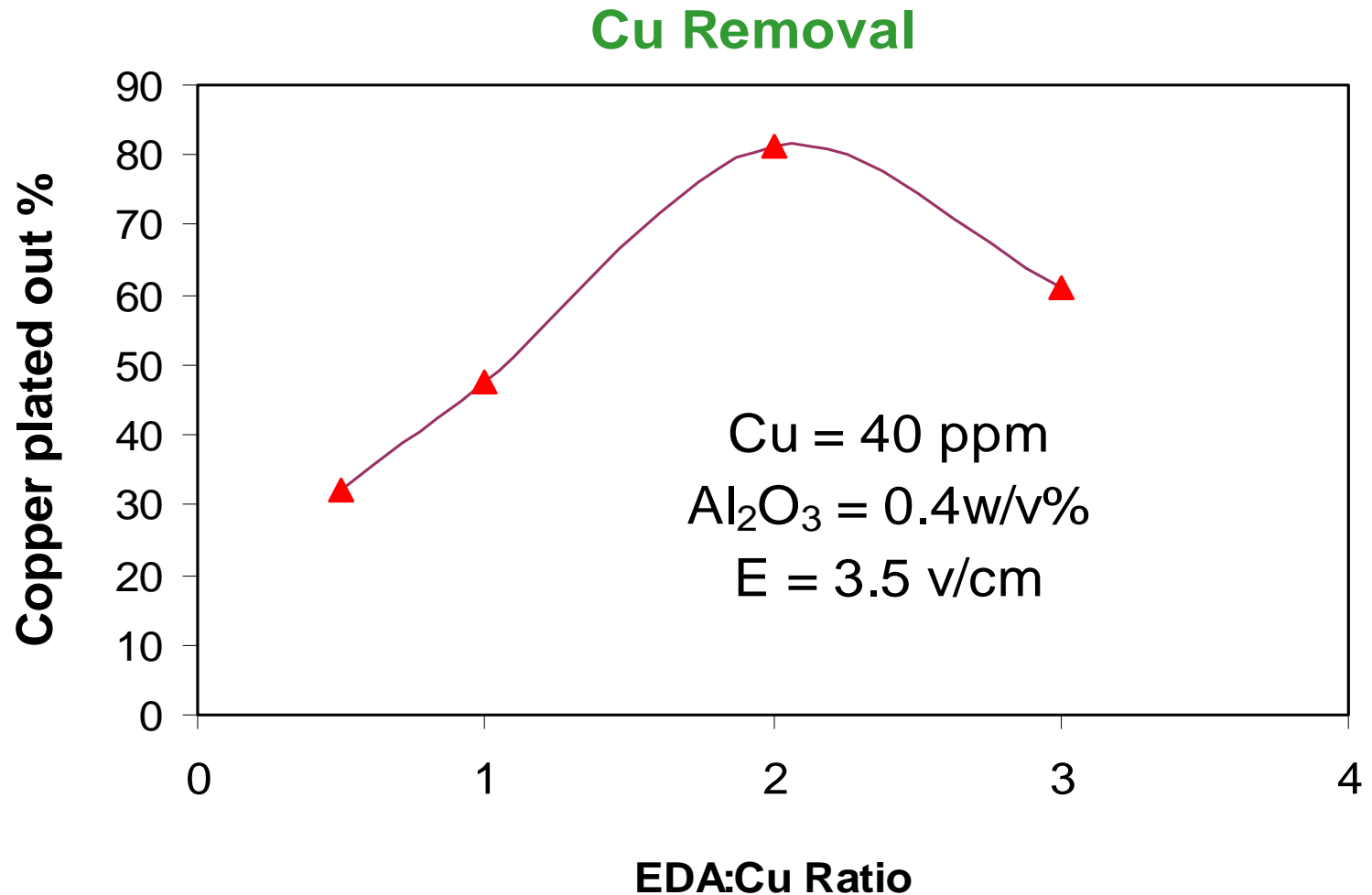
Effect of Copper Level on Cu Removal by Deposition



- Extent of Cu removal by deposition is adversely affected by the presence of particles.



Effect of EDA:Cu Ratio on Particulate & Cu Removal -- (1)

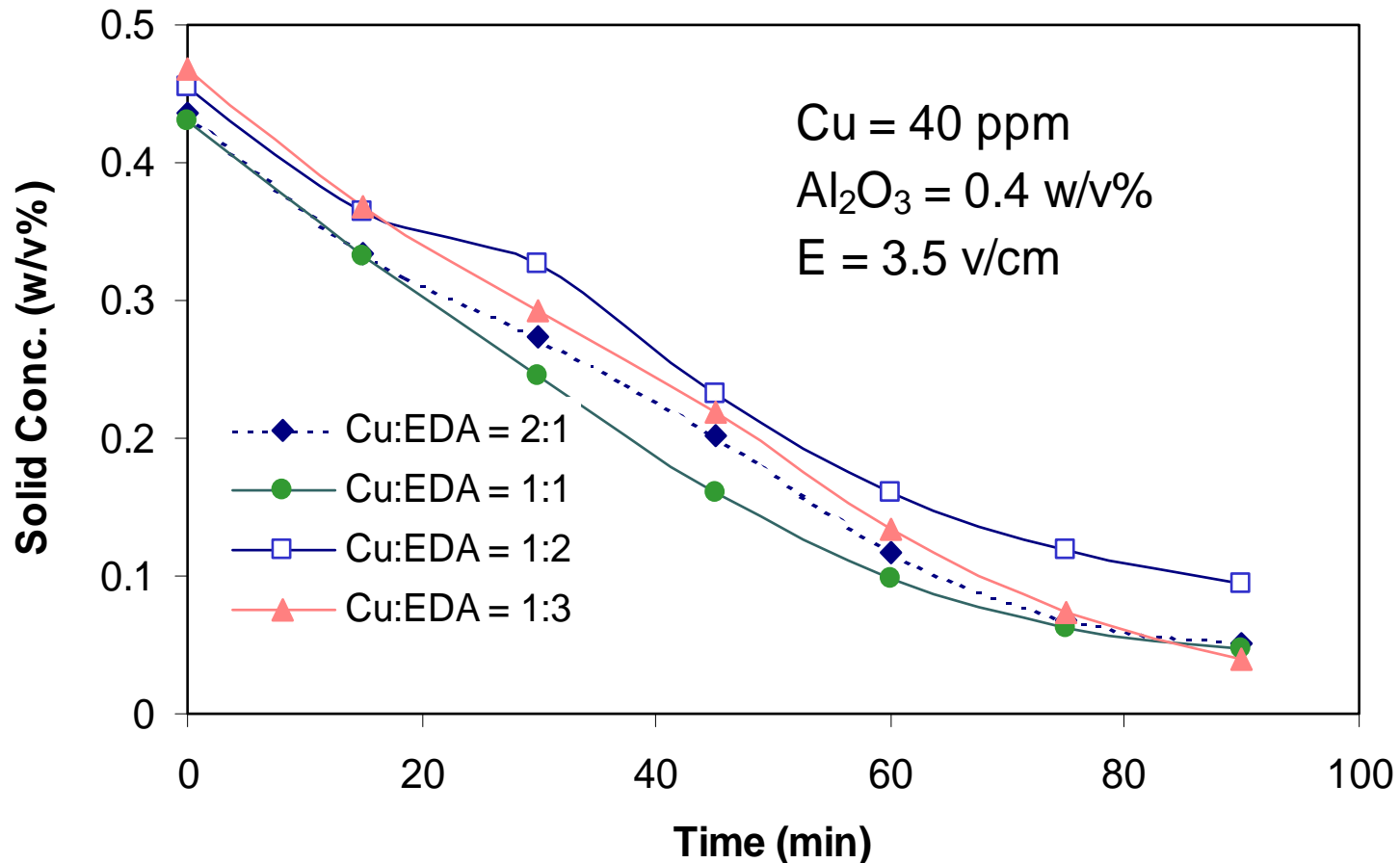


- The EDA:Cu Ratio appears to influence the extent of copper removal by plating



Effect of EDA:Cu Ratio on Particulate & Cu Removal -- (2)

Effect of Cu:EDA Ratio on Particulate Removal



- The EDA:Cu Ratio does not appear to influence particulate removal



- Aqueous Alumina suspensions can be destabilized by the application of an electric field.
- The pH changes created and maintained by the use of membranes is critical to the success of the electrocoagulation process.
- Copper can be removed simultaneously with the solids, either by in situ precipitation or by plating out onto the cathode.
- The extent of copper removal by plating is affected by the type of the organic complexant that may be present in the CMP slurry as well as the charge on the membrane used.

